

CATV Line Amplifiers/Power Inserters 3 kA *SIDACTor*[®] Device



This *SIDACTor* device is a 3000 A solid state protection device offered in a non-isolated TO-263 (D²) package. It protects equipment located in the severe surge environment of CATV (Community Antenna TV) systems and antenna locations.

Electrical Parameters

Part Number *	V _{DRM} Volts	V _S Volts	V _T Volts	I _{DRM} μ Amps	I _S mAmps	I _T Amps **	I _H mAmps
P1500NEL	140	180	4	5	800	2.2/25	50
P1900NEL	140	220	4	5	800	2.2/25	50
P2300NEL	180	260	4	5	800	2.2/25	50

SIDACTor Devices

* "L" in part number indicates RoHS compliance. For non-RoHS compliant device, delete "L" from part number.
For surge ratings, see table below.

** I_T is a free air rating; heat sink I_T rating is 25 A.

General Notes:

- All measurements are made at an ambient temperature of 25 °C. I_{PP} applies to -40 °C through +85 °C temperature range.
- I_{PP} is a repetitive surge rating and is guaranteed for the life of the product.
- Listed *SIDACTor* devices are bi-directional. All electrical parameters and surge ratings apply to forward and reverse polarities.
- V_{DRM} is measured at I_{DRM}.
- V_S is measured at 100 V/ μ s.
- Special voltage (V_S and V_{DRM}) and holding current (I_H) requirements are available upon request.

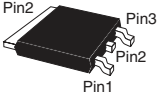
Surge Ratings in Amps

Series	I _{PP}		I _{TSM} 50 / 60 Hz	di/dt
	8x20 *	1.2x50 **		
	Amps		Amps	Amps/ μ s
E	3000		400	500

* Current waveform in μ s

** Voltage waveform in μ s

Thermal Conditions

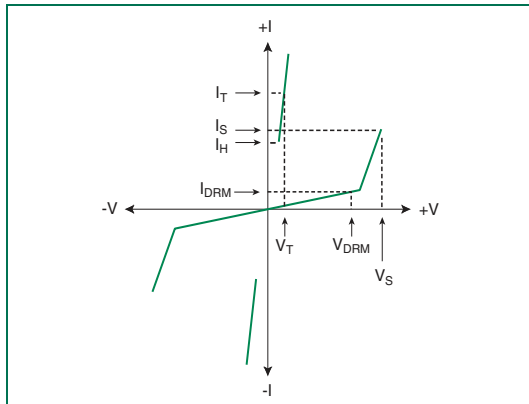
Package	Symbol	Parameter	Value	Unit
TO-263 D ² PAK 	T _J	Operating Junction Temperature Range	-40 to +150	°C
	T _S	Storage Temperature Range	-65 to +150	°C
	T _C	Maximum Case Temperature	100	°C
	R _{θJC} *	Thermal Resistance: Junction to Case	1.7	°C/W
	R _{θJA}	Thermal Resistance: Junction to Ambient	56	°C/W

* R_{θJC} rating assumes the use of a heat sink and on state mode for extended time at 25 A, with average power dissipation of 29.125 W.

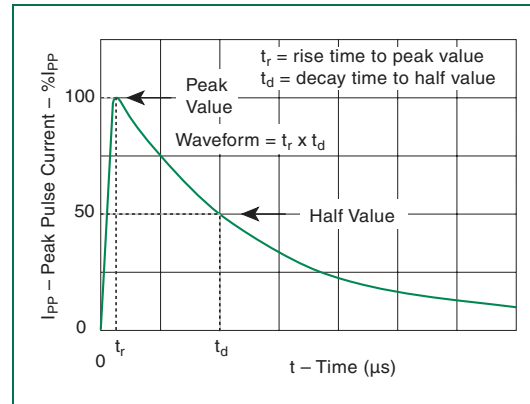
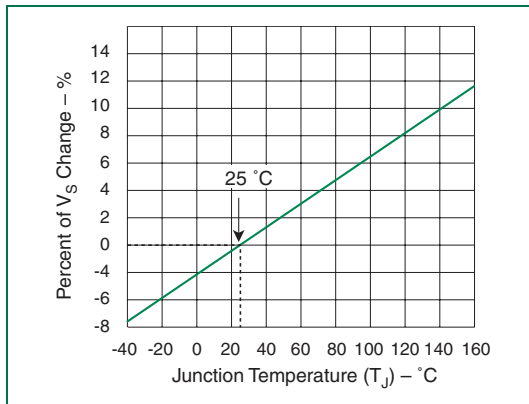
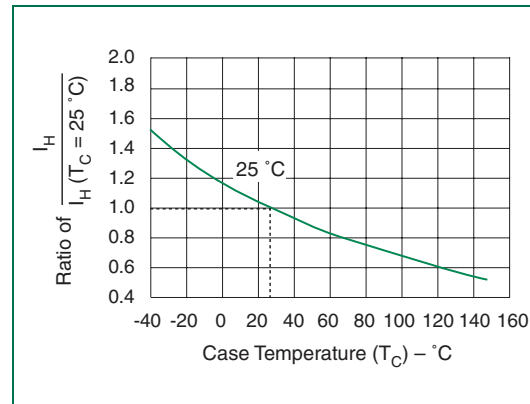
Capacitance Values

Part Number	pF	
	MIN	MAX
P1500NEL	260	650
P1900NEL	260	650
P2300NEL	350	600

Note: Off-state capacitance (C_O) is measured at 1 MHz with a 2 V bias.



V-I Characteristics


 t_r x t_d Pulse Waveform

 Normalized V_S Change versus Junction Temperature


Normalized DC Holding Current versus Case Temperature